

Low Capactionce 1-Line Bi-directional TVS Diode

Features

- Ultra small package: 1.0x0.6x0.5mm
- Ultra low capacitance: 0.3pF typical
- Ultra low leakage: nA level
- Low operating voltage: ±5V *
- Low clamping voltage *
- 2-pin leadless package
- Complies with following standards: *
 - IEC 61000-4-2 (ESD) immunity test Air discharge: ±20kV

Contact discharge: ±15kV

- IEC61000-4-5 (Lightning) 4A (8/20µs)
- **RoHS** Compliant
- Lead Finish: NiPdAu

Ordering Information

Part Number	Qty per Reel	Reel Size
RCLAMP0521P	10000 or 3000	7″

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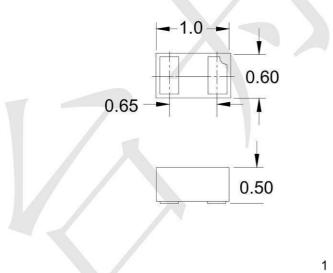
Mechanical Characteristics

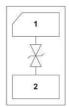
- * Package: DFN1006-2 (0402)
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below

Applications

- Smart phones
- **Display Ports**
- **MDDI** Ports *
- **USB** Ports *
- Digital Video Interface (DVI)
- PCI Express and Serial SATA Ports

Dimensions and Pin Configuration







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Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	80	w
Peak Pulse Current (8/20µs)	Ірр	4	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±20 ±15	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

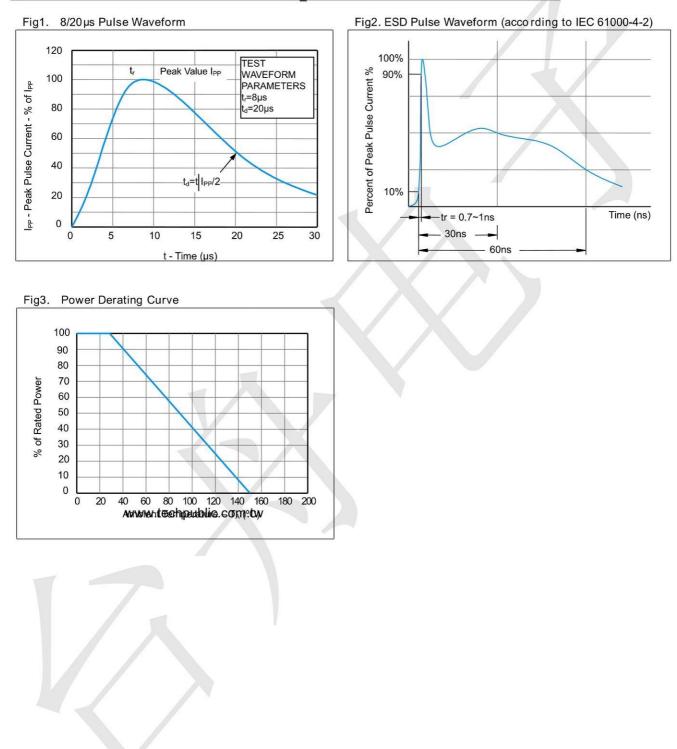
Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	5.8	7.5	9	v	IT = 1mA
Reverse Leakage Current	I _R			0.08	μA	VRWM = 5V
Clamping Voltage	Vc	$\overline{\mathbf{X}}$		12	v	IPP = 1A (8 x 20µs pulse)
Clamping Voltage	Vc			21	V	IPP = 4A (8 x 20us pulse)
Junction Capacitance	CJ		0.3		pF	VR = 0V, f = 1MHz IO to IO



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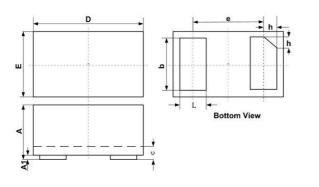
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



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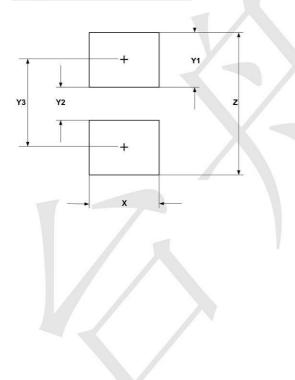
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DFN1006-2 Package Outline Drawing (0402)



	DIMENSIONS					
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
А	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
С	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
е	0.65 BSC			(.026 BS	c
Е	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern



SYM	DIMENSIONS				
5111	MILLIMETERS	INCHES			
X	0.60	0.024			
Y1	0.50	0.020			
Y2	0.30	0.012			
Y3	0.80	0.032			
Z	1.30	0.052			